

Enhancing of catalytic activity of MoS₂ single layers through spontaneous oxidation under ambient conditions

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The chemical inertness of the defect-free basal plane confers environmental stability to MoS₂ single layers, but it also limits their chemical versatility and catalytic activity. The stability of pristine MoS₂ basal plane against oxidation under ambient conditions is a widely accepted assumption however, we found [1] that oxygen gradually incorporates into the basal plane of 2D MoS₂ crystals through a substitutional oxidation reaction, by replacing individual sulfur atoms, while fully preserving the original crystal lattice during ambient exposure. The scanning tunneling microscopy measurements and DFT calculations reveal a slow oxygen-substitution reaction, during which individual sulfur atoms are replaced one by one by oxygen, giving rise to solid-solution-type 2D MoS_{2-x}O_x crystals. Oxygen substitution sites present all over the basal plane act as single-atom reaction centers, substantially increasing the catalytic activity of the entire MoS₂ basal plane for the electrochemical H₂ evolution reaction. The observed oxidation process enables the chemical modification of single atomic sites of 2D crystals opening new routes towards their efficient defect engineering. This work was supported by the Russian Scientific Foundation (project no. 18-73-10135).

[1] Janos Peto, Tamas Ollar, Peter Vancso, Zakhar I. Popov, Gabor Zsolt Magda, Gergely Dobrik, Chanyong Hwang, Pavel B. Sorokin & Levente Tapasztó, *Nature chemistry* 10.1038/s41557-018-0136-2 (2018).